

PRODUCT DATASHEET

Digital MEMS Microphone

IM4030T261-MA14

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1. Introduction

1.1 Overview

IM4030T261-MA14 is an omnidirectional, Top - ported, PDM digital output MEMS microphone. It has high performance and reliability.

Other high-performance specifications include 120 dB SPL acoustic overload point in high performance mode, ± 1 dB sensitivity tolerance and enhanced immunity to both radiated and conducted RF interface.

Excellent acoustic performance, along with the compact size(4.00*3.00*1.00mm) is best-suited for a wide range of consumer electronic products, offering a product with high-quality to meet the application requirement.

1.2 Product Features

- PDM Output
- High SNR
- RF Protection
- RoHS/Halogen free compliant
- Standard SMD Reflow

1.3 Typical Application

- Microphone Arrays
- Tablets
- Digital Still Cameras
- Headsets
- Notebook PCs
- Smart home devices, Internet of Things

2. Absolute Maximum Ratings

Parameter	Absolute Maximum Rating	Units
Voltage Range of VDD to Ground	-0.3 to +4.0	V
DATA, CLOCK, L/R to Ground	-0.3 to +4.0	V
Input Current	± 5	mA
Temperature Range	-40 to +100	°C

Stresses exceeding these “Absolute Maximum Ratings” could cause permanent damage to the microphone. These are stress rating only. Functional operation at these or any other conditions beyond those indicated under “Absolute and Electrical Characteristics” is not implied. Exposure beyond those indicated under “Acoustic and Electrical Characteristics” for extended periods may affect microphone reliability.

3. Acoustic and Electrical Characteristics

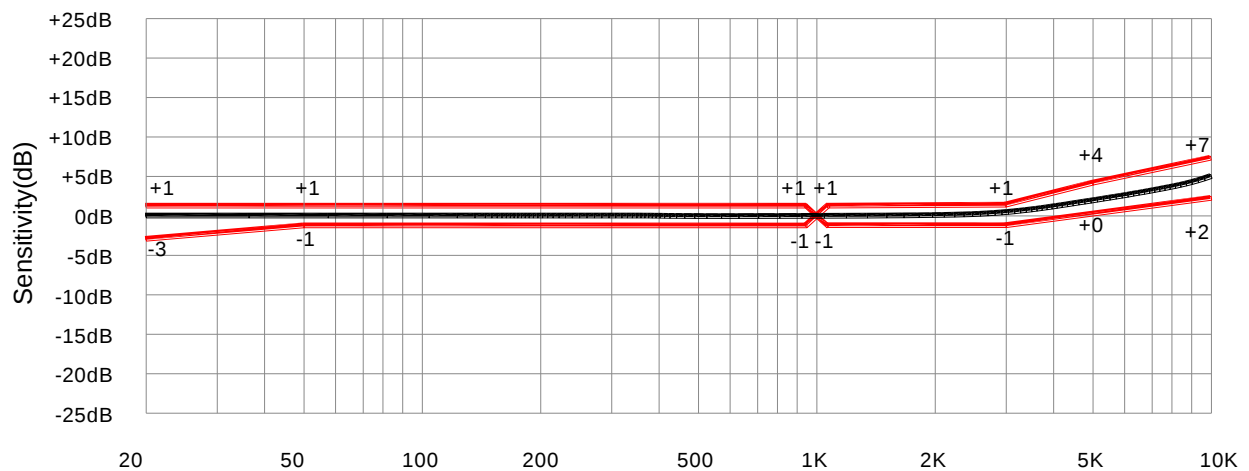
(Test Conditions: 23±2°C, 55±20% R.H. V_{DD}=2.0V. f_{clock}=2.4MHz)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Directivity	D(θ)	Omni-Directional				
Sensitivity	S	94dB SPL @1KHz	-27	-26	-25	dBFS
Supply Voltage	V _{DD}	-	1.6	-	3.6	V
Current Consumption	I _{DD}	-	-	-	0.75	mA
S/N Ratio	S/N	94dB SPL @1KHz (A-weighted)	-	65	-	dB
Sleep Current	I _{SLEEP}	F _{CLOCK} < 1 kHz	-	3	4	uA
Total Harmonic Distortion	THD	94dB SPL @1KHz	-	0.2	-	%
Acoustic Overload Point	AOP	10% THD @ 1 kHz	-	120	-	dB SPL
Power Supply Rejection	PSR	100 mVpp square wave @ 217 Hz, A-weighted	-	-90	-	dBFS
Fall-asleep Time	-	(F _{CLOCK} < 1KHz)	-	-	50	usec

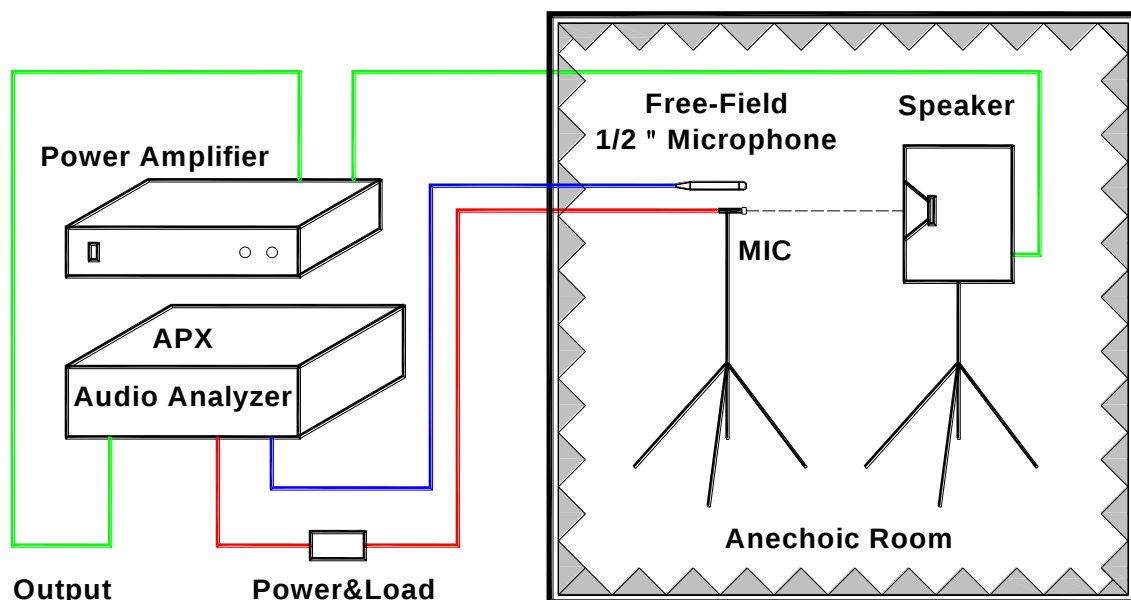
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Wake-up Time	-	$f_{\text{clock}}=2.4\text{MHz}$	-	-	52	msec
Short Circuit Current	I_{SC}	Grounded Data Pin	-	1	10	mA
Output Load	C_{LOAD}	-	-	-	100	pF
Data Format	-	-	1-Bit PDM			
Clock Frequency	F_{CLOCK}	-	1.024	2.4	3.25	MHz
Clock Duty Cycle	F_{DC}	-	40	-	60	%
Clock Rise Time	t_{CR}	-	-	-	10	nsec
Clock Fall Time	t_{CF}	-	-	-	10	nsec
Logic Input Hight	V_{IH}	-	$0.75 \times V_{\text{DD}}$	-	-	V
Logic Input Low	V_{IL}	-	-	-	$0.25 \times V_{\text{DD}}$	V
Logic Output Hight	V_{OH}	-	$0.9 \times V_{\text{DD}}$	-	-	V
Logic Output Low	V_{OL}	-	-	-	$0.1 \times V_{\text{DD}}$	V
Delay Time for Valid Data	t_{DV}	-	18	-	40	nsec
Delay Time for Hight z	t_{DH}	-	0	-	15	nsec

4. Frequency Response Curve

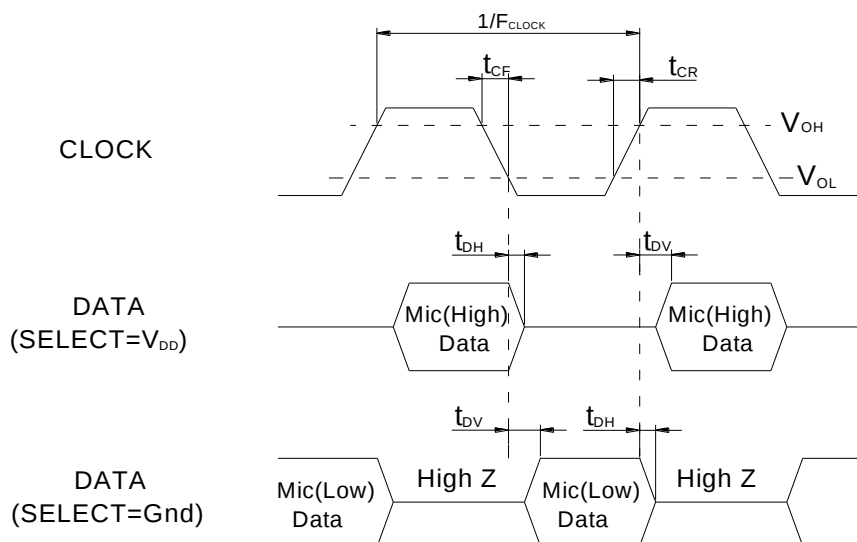
Frequency Response (0dB=1V/Pa)



5. Test Setup Drawing

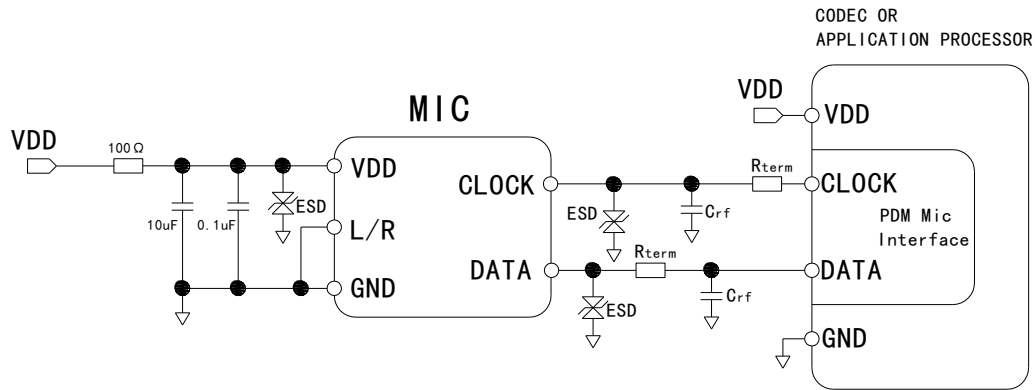


6. Timing Diagram

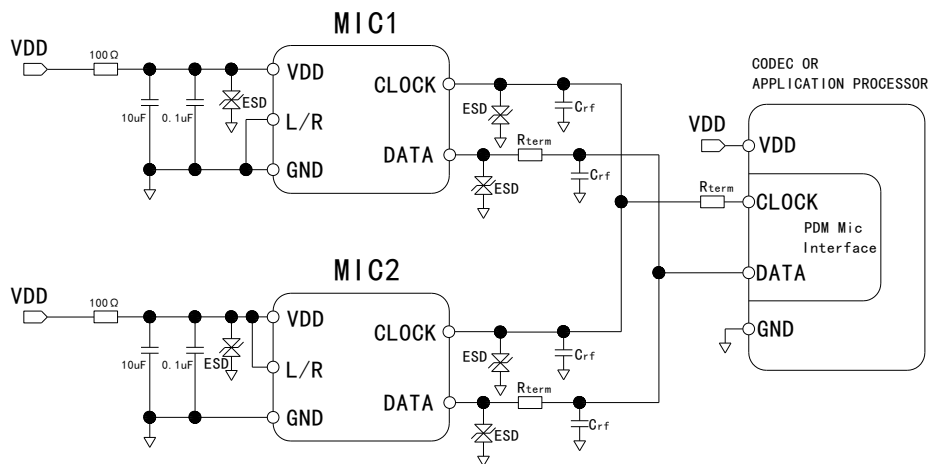


Microphone	Select (L/R)	Asserts DATA On	Latch DATA On
Mic(High)	V _{DD}	Rising clock edge	Falling clock edge
Mic(Low)	GND	Falling clock edge	Rising clock edge

8. Recommended interface circuit



Single MIC

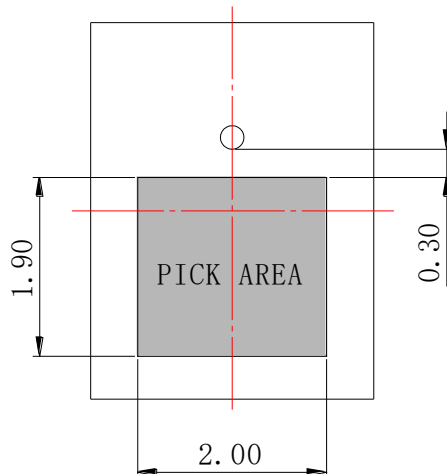


Double MIC

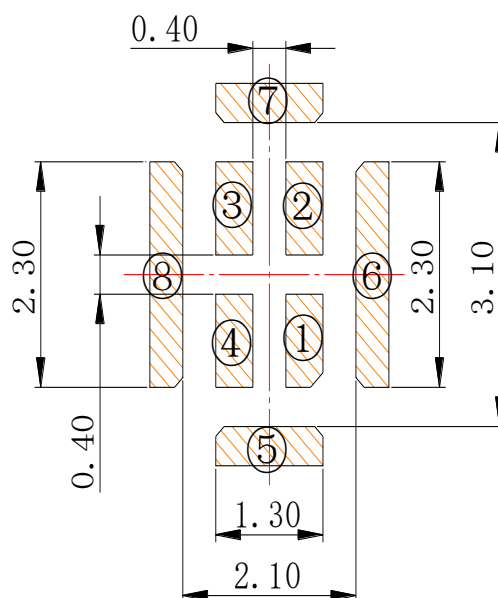
Notes:

1. Power supply decoupling capacitors (0.1μF、10μF capacitor, 100Ω resistor and the ESD diode) should be placed as near as possible to VDD of the device. (common design practice)
2. C_{rf} and R_{term} are all used for debugging. Actually their values or NC are based on the debugging result.

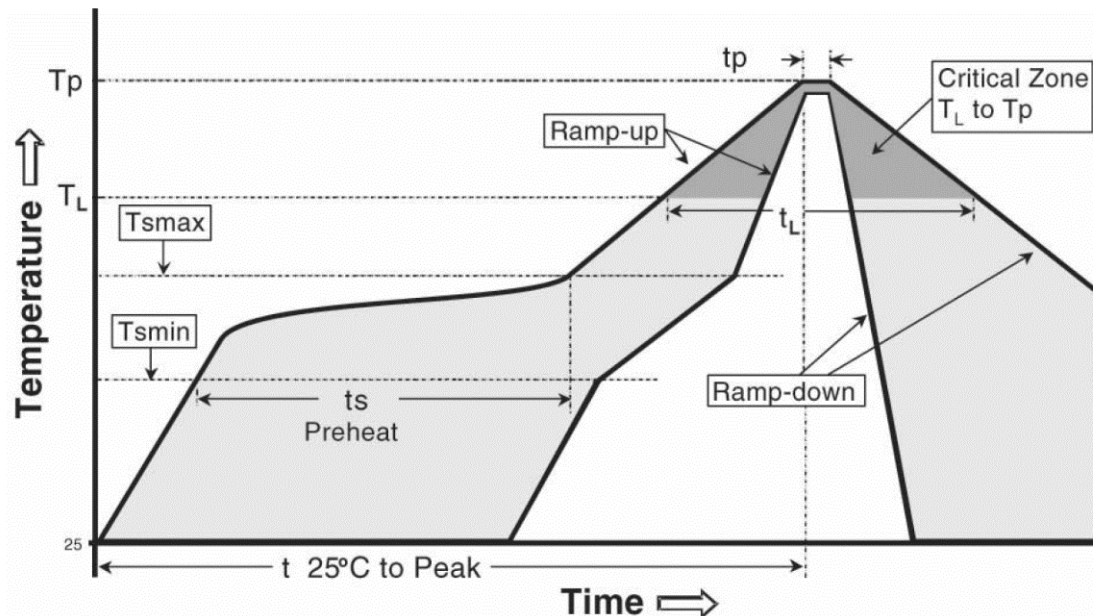
9. Vacuum nozzle pickup location



10. Example solder stencil pattern



11. Recommended Reflow Profile



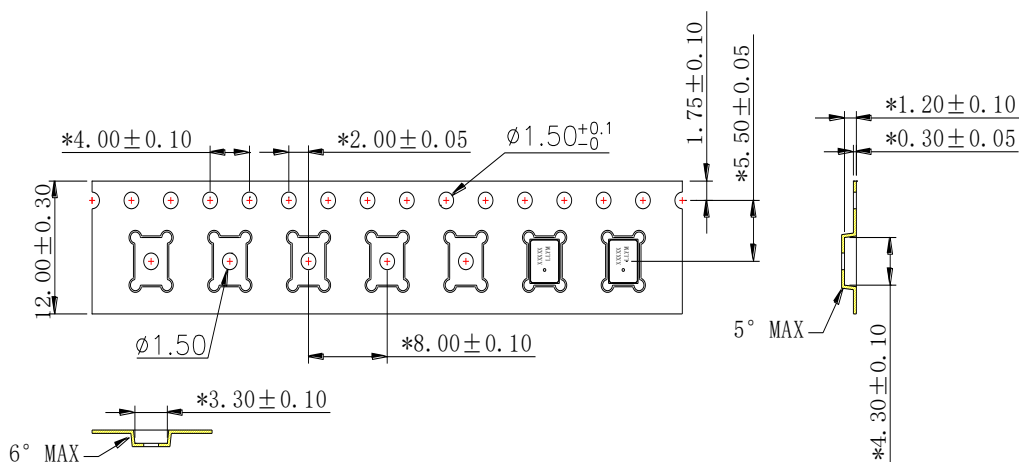
Profile Feature	Pb-Free
Average Ramp-up rate (T_{smax} to T_P)	3°C/second max.
Preheat	
Temperature Min (T_{smin})	150°C
Temperature Max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60-180 seconds
Time maintained above:	
Temperature (T_L)	217°C
Time (t_L)	60-150 seconds
Peak Temperature (T_P)	260°C
Time within 5°C of actual Peak Temperature (t_P)	20-40 seconds
Ramp-down rate(T_P to T_{smax})	6°C/second max
Time 25°C to Peak Temperature	8 minutes max

Notes:

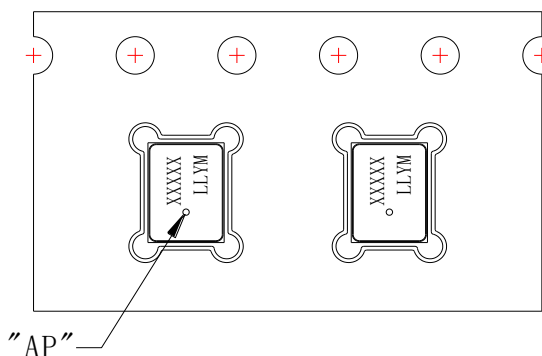
1. Pulling vacuum over acoustical hole of the microphone is not allowed, because the device can be damaged by vacuum.
2. Wash the board after reflow process is not allowed, because board washing and cleaning agents can damage the device. Device should not be exposed to ultrasonic processing or cleaning.
3. Recommended number of reflow is no more than 3 times.

12. Packaging Specifications

11.1. Tape Specification

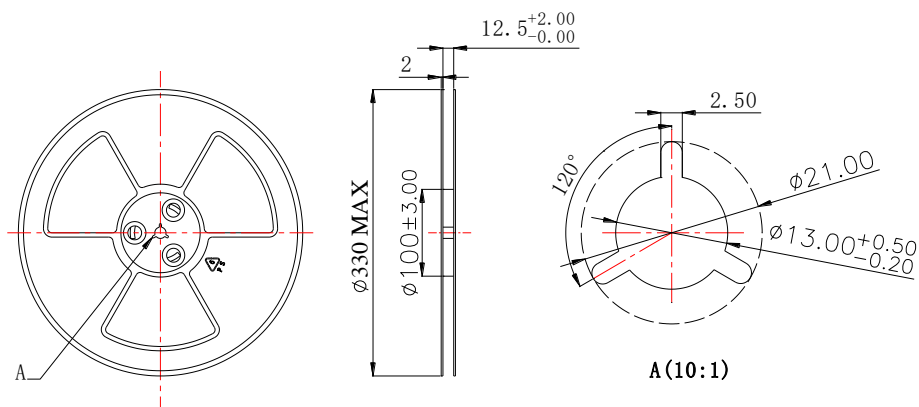


Line	Character	Description
1	XXXXXX	Unique Trace Code
2	LL	Identify Code
3	Y	Year
4	M	Month

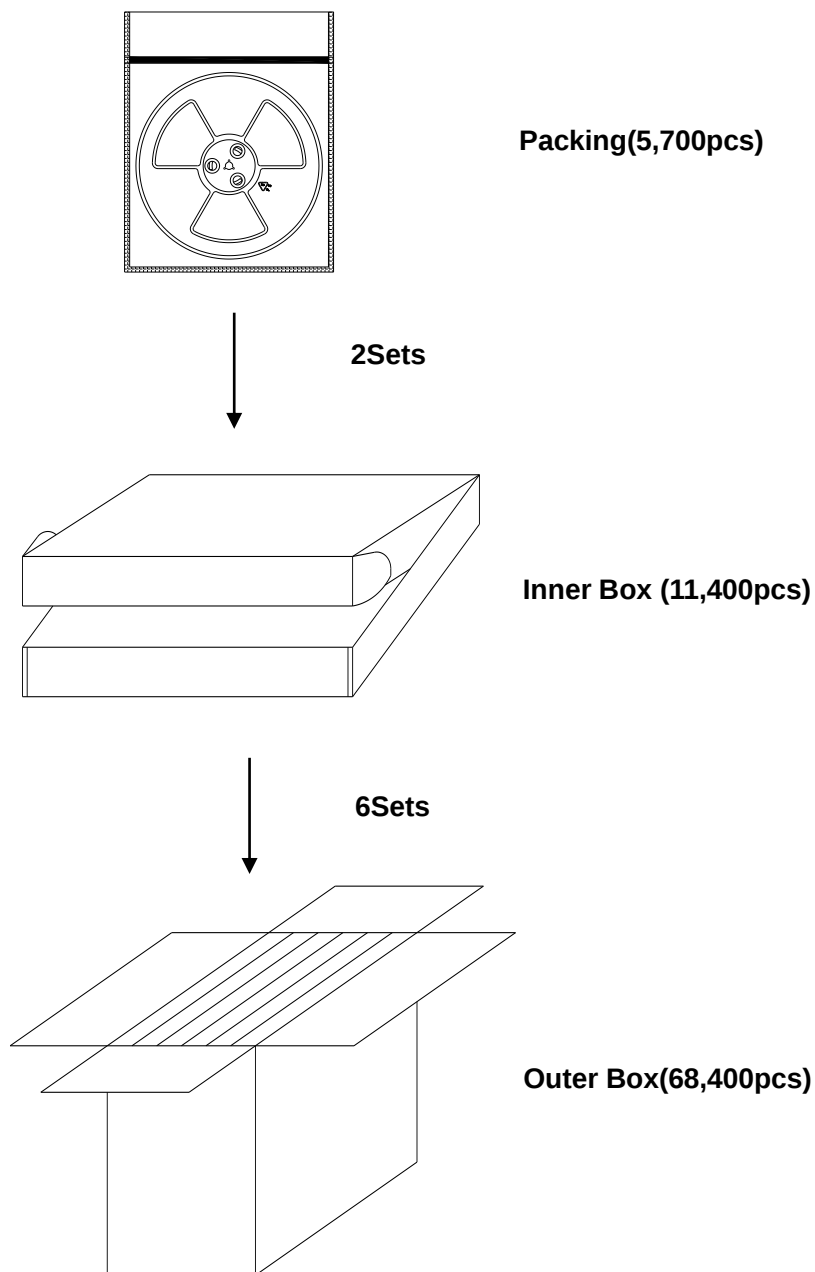


11.2. Reel Dimension

13" reel dimensions (unit:mm)



11.3. The Content of Box(13" reel)



Qty/ Reel	Qty/ One Inner Box	Qty/ Outer Box (Six Inner Box)
5,700 pcs	11,400 pcs	68,400 pcs
Φ 330mm	355 × 340 × 45mm	365 × 290 × 370mm

13. Reliability Specifications

Test Item	Detail
Thermal Shock	100 cycles of air-air thermal shock from -40°C to +105°C with 15 minute soaks.
High Temperature Storage	+105°C environment for 500 hours.
Low Temperature Storage	-40°C environment for 500 hours.
High Temperature Test	+105°C environment while under bias for 500 hours.
Low Temperature Test	-40°C environment while under bias for 500 hours.
Humidity Test	+85°C/85% R.H. environment while under bias for 500 hours.
Vibration Test	16 minutes in each X, Y, Z axis from 20 to 2,000 Hz with peak acceleration of 20G.
Drop Test	1.5-meter height onto a concrete surface each time at three directions in state of packaging.
Reflow Test	5 reflow cycles with peak temperature of +260°C.
ESD Test	Under C=150pF, R=330ohm. Tested to $\pm 8\text{kV}$ contact to the case and tested to $\pm 2\text{kV}$ contact to I/O terminals. 10 times. Grounding.

Note: The microphone sensitivity after stress must deviate by no more than $\pm 3\text{dB}$ from the initial value.

14. VERSION HISTORY:

Version	Description	Date
1.0	Initial release	2024.5